

**SCOPE: CMOS VOLTAGE CONVERTER**

| <u>Device Type</u> | <u>Generic Number</u> | <u>SMD Number</u> |
|--------------------|-----------------------|-------------------|
| 01                 | MAX1044(x)/883B       | 5962-3870701      |

**Case Outline(s).** The case outlines shall be designated in Mil-Std-1835 and as follows:

| <u>Outline Letter</u> | <u>Mil-Std-1835</u>    | <u>Case Outline</u> | <u>Package Code</u> |
|-----------------------|------------------------|---------------------|---------------------|
| Maxim SMD             |                        |                     |                     |
| JA P                  | GDIP1-T08 or CDIP2-T08 | 8 LEAD CERDIP       | J08                 |
| TV G                  | MACY1-8X               | 8 LEAD CAN          | 8 TO 99             |

**Absolute Maximum Ratings**

Voltage Referenced to V<sup>-</sup>

|  |   |
|--|---|
| V <sub>DD</sub> TO GND .....                                   | 9.5V  |
| Input Voltage (Boost, LV and OSC) <sup>1/</sup> .....          | (-0.3Vdc) ≤ V <sub>IN</sub> ≤ V <sup>+</sup> + 0.3Vdc |
| Output short circuit duration (V <sup>+</sup> ≤ 5.5V dc) ..... | Continuous  |
| Current into LV pin .....                                      | 20μA  |
| Lead Temperature (soldering, 10 seconds) .....                 | +300°C  |
| Storage Temperature .....                                      | -65°C to +150°C                                       |
| Continuous Power Dissipation .....                             | T <sub>A</sub> = +70°C                                |
| 8 lead CERDIP (derate 8.0mW/°C above +70°C) .....              | 640mW   |
| 8 lead Can (derate 6.67mW/°C above +70°C) .....                | 533mW   |
| Junction Temperature T <sub>J</sub> .....                      | +150°C  |
| Thermal Resistance, Junction to Case, Θ <sub>JC</sub> :        |   |
| Case Outline 8 lead CERDIP .....                               | 55°C/W  |
| Case Outline 8 lead Can .....                                  | 45°C/W  |
| Thermal Resistance, Junction to Ambient, Θ <sub>JA</sub> :     |   |
| Case Outline 8 lead CERDIP .....                               | 125°C/W   |
| Case Outline 8 lead Can .....                                  | 150°C/W   |

**Recommended Operating Conditions**

|   |                    |
|---|--------------------|
| Ambient Operating Range (T <sub>A</sub> ) ..... | -55°C to +125°C    |
| Supply Voltage Range (V <sup>+</sup> ) .....    | 1.5V dc to 9.0V dc |

<sup>1/</sup> Connecting any input terminal to voltages greater than V<sup>+</sup> or less than ground may cause destructive latchup. It is recommended that no inputs from sources operating from external supplies be applied prior to power-up of the device.

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TABLE 1. ELECTRICAL TESTS:**

| TEST                           | Symbol                       | CONDITIONS   | Group A Subgroup | Device type | Limits Min | Limits Max | Units |
|--------------------------------|------------------------------|--|------------------|-------------|------------|------------|-------|
|                                |                              | -55 °C <=T <sub>A</sub> <= +125°C<br>V <sup>+</sup> =+5.0V<br>Unless otherwise specified |                  |             |            |            |       |
| <b>SWITCH</b>                  |                              |  |                  |             |            |            |       |
| Minimum Supply Voltage         | I <sub>CC</sub>              | R <sub>L</sub> =∞ Boost and OSC, no connection   | 1                | All         |            | 200        | μA    |
| Minimum Supply Voltage         | V+Min                        | R <sub>L</sub> =10kΩ   | 1,2,3            | All         | 1.5        |            | V     |
| Maximum Supply Voltage         | V+Max                        | R <sub>L</sub> =10kΩ   | 1,2,3            | All         |            | 9.0        | V     |
| Output Resistance              | R <sub>OUT</sub>             | I <sub>L</sub> =20mA, f <sub>OSC</sub> =5.0kHz   | 1<br>2,3         | All         |            | 100<br>150 | Ω     |
|                                |                              | I <sub>L</sub> =3.0mA, f <sub>OSC</sub> =1.0kHz, V <sup>+</sup> =2V                      | 1,2,3            |             |            | 400        |       |
| Oscillator Frequency<br>NOTE 2 | f <sub>OSC</sub>             | C <sub>OSC</sub> =1.0pF, V <sup>+</sup> =5.0V  | 4,5,6            | All         | 5.0        |            | kHz   |
|                                |                              | C <sub>OSC</sub> =1.0pF, V <sup>+</sup> =5.0V  | 4,5,6            | All         | 1.0        |            |       |
| Power Efficiency               | P <sub>EFF</sub>             | R <sub>L</sub> =5kΩ, f <sub>OSC</sub> =5kHz  | 1                | All         | 95         |            | %     |
| Voltage Conversion Efficiency  | V <sub>C<sub>EFF</sub></sub> | R <sub>L</sub> =∞  | 1                | All         | 97         |            | %     |
| Oscillator Sink Current        | I <sub>SINK</sub>            | V <sub>OSC</sub> =V+, BOOST=0V   | 1,2,3            | All         | 0.1        | 3.0        | μA    |
|                                |                              | V <sub>OSC</sub> =V+, BOOST=V+   | 1,2,3            | All         | 1.0        | 20         |       |
| Oscillator Source Current      | I <sub>SOURCE</sub>          | V <sub>OSC</sub> =0V, BOOST=0V   | 1,2,3            | All         | 0.1        | 3.0        | μA    |
|                                |                              | V <sub>OSC</sub> =0V, BOOST=V+   | 1,2,3            | All         | 1.0        | 20         |       |

NOTE 2: f<sub>OSC</sub> is tested with C<sub>OSC</sub>=100pF to minimize the effects of test fixture capacitance loading. The 1.0pF frequency is correlated to this 100pF test point and is intended to simulate the capacitance at the OSC pin when the device is plugged into a test socket and no external capacitor is used.

| Package      | ORDERING INFORMATION: | SMD Number      |
|--------------|-----------------------|-----------------|
| 8 pin CERDIP | MAX1044MJA/883B       | 5962-3870701MPA |
| 8 pin Can    | MAX1044MTV/883B       | 5962-3870701MGC |

**TERMINAL CONNECTIONS:**

|   | J8    | TO99  |
|---|-------|-------|
| 1 | BOOST | BOOST |
| 2 | CAP+  | CAP+  |
| 3 | GND   | GND   |
| 4 | CAP-  | CAP-  |
| 5 | VOUT  | VOUT  |
| 6 | LV    | LV    |
| 7 | OSC   | OSC   |
| 8 | V+    | V+    |

## QUALITY ASSURANCE

Sampling and inspection procedures shall be in accordance with MIL-Prf-38535, Appendix A as specified in Mil-Std-883.

Screening shall be in accordance with Method 5004 of Mil-Std-883. Burn-in test Method 1015:

1. Test Condition, A, B, C, or D.
2. TA = +125°C minimum.
3. Interim and final electrical test requirements shall be specified in Table 2.

Quality conformance inspection shall be in accordance with Method 5005 of Mil-Std-883, including Groups A, B, C, and D inspection.

Group A inspection:

1. Tests as specified in Table 2.
2. Selected subgroups in Table 1, Method 5005 of Mil-Std-883 shall be omitted.

Group C and D inspections:

- a. End-point electrical parameters shall be specified in Table 1.
- b. Steady-state life test, Method 1005 of Mil-Std-883:
  1. Test condition A, B, C, D.
  2. TA = +125°C, minimum.
  3. Test duration, 1000 hours, except as permitted by Method 1005 of Mil-Std-883.

**TABLE 2. ELECTRICAL TEST REQUIREMENTS**

| Mil-Std-883 Test Requirements                                | Subgroups<br>per Method 5005, Table 1 |
|--|---------------------------------------|
| Interim Electric Parameters<br>Method 5004                   | 1                                     |
| Final Electrical Parameters<br>Method 5005                   | 1*, 2, 3, 4, 5, 6                     |
| Group A Test Requirements<br>Method 5005                     | 1, 2, 3, 4, 5, 6                      |
| Group C and D End-Point Electrical Parameters<br>Method 5005 | 1                                     |

\* PDA applies to Subgroup 1 only.